Preferred Devices

General Purpose Transistors

PNP Silicon

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	BC856 BC857 58, BC859	V _{CEO}	-65 -45 -30	>
Collector-Base Voltage BC856 BC857 BC858, BC859		V _{CBO}	-80 -50 -30	V
Emitter-Base Voltage	V _{EBO}	-5.0	V	
Collector Current - Continu	I _C	-100	mAdc	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

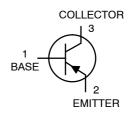
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



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SOT-23 (TO-236AB) CASE 318 STYLE 6

MARKING DIAGRAM



xx = Device Code

xx = (Refer to page 5)

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

1

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characterist	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS				•	I.	
Collector – Emitter Breakdown Voltage (I _C = -10 mA) BC856 Series BC857 Series BC858, BC859 Series		V _{(BR)CEO}	-65 -45 -30	- - -	- - -	V
Collector – Emitter Breakdown Voltage BC856 Series BC857A, BC857B Only BC858, BC859 Series		V _{(BR)CES}	-80 -50 -30	- - -	- - -	V
Collector – Base Breakdown Voltage (I _C = –10 μA)	BC856 Series BC857 Series BC858, BC859 Series	V _{(BR)CBO}	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage BC856 Series (I _E = -1.0 μA) BC857 Series BC858, BC859 Series		V _{(BR)EBO}	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current ($V_{CB} = -30 \text{ V}$) ($V_{CB} = -30 \text{ V}$, T_A	I _{CBO}	_ _	- -	-15 -4.0	nA μA	
ON CHARACTERISTICS	•		•	•		
DC Current Gain BC856A, BC857A, BC858A $(I_C = -10 \ \mu\text{A}, \ V_{CE} = -5.0 \ \text{V})$ BC856B, BC857B, BC858B BC857C, BC858C		h _{FE}	- - -	90 150 270	- - -	-
$(I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ BC856 BC856 BC857		125 220 420	180 290 520	250 475 800		
Collector – Emitter Saturation Voltage (I_C = -10 mA, I_B = -0.5 mA) (I_C = -100 mA, I_B = -5.0 mA)	V _{CE(sat)}	- -	- -	-0.3 -0.65	V	
Base – Emitter Saturation Voltage (I_C = -10 mA, I_B = -0.5 mA) (I_C = -100 mA, I_B = -5.0 mA)	V _{BE(sat)}	- -	-0.7 -0.9	- -	V	
Base – Emitter On Voltage (I_C = -2.0 mA, V_{CE} = -5.0 V) (I_C = -10 mA, V_{CE} = -5.0 V)	V _{BE(on)}	-0.6 -	- -	-0.75 -0.82	V	
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product (I _C = -10 mA, V _{CE} = -5.0 Vdc, f = 100 l	f _T	100	-	-	MHz	
Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz)	C _{ob}	-	-	4.5	pF	
Noise Figure (I_C = -0.2 mA, V_{CE} = -5.0 Vdc, R_S = 2.0 BC856 BC859	NF	_ _		10 4.0	dB	

BC857/BC858/BC859

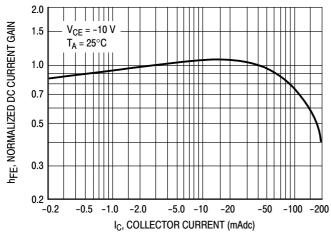


Figure 1. Normalized DC Current Gain

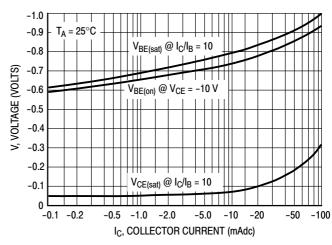


Figure 2. "Saturation" and "On" Voltages

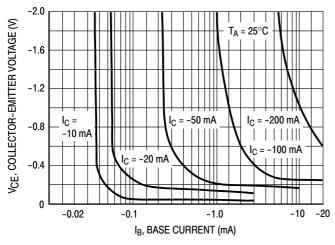


Figure 3. Collector Saturation Region

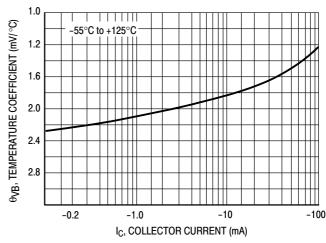


Figure 4. Base-Emitter Temperature Coefficient

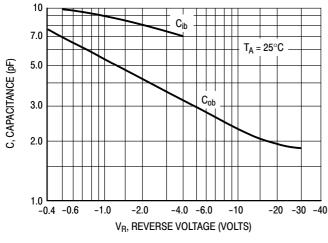


Figure 5. Capacitances

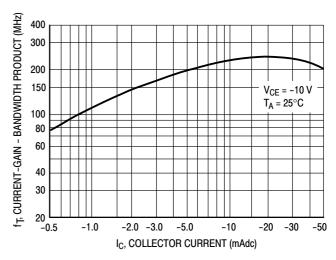


Figure 6. Current-Gain - Bandwidth Product

BC856

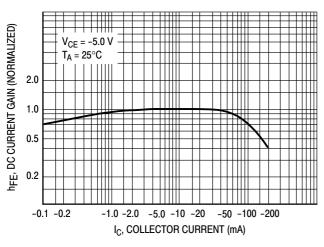


Figure 7. DC Current Gain

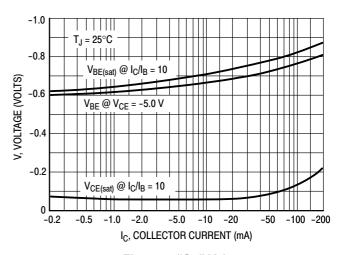


Figure 8. "On" Voltage

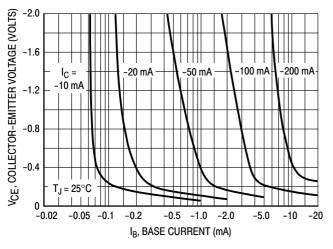


Figure 9. Collector Saturation Region

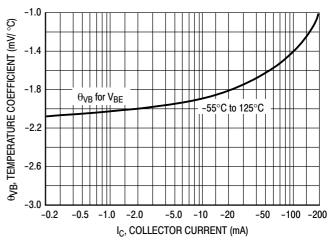


Figure 10. Base-Emitter Temperature Coefficient

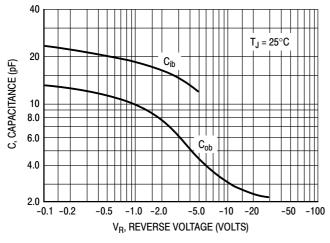


Figure 11. Capacitance

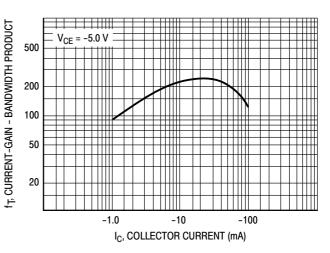


Figure 12. Current-Gain - Bandwidth Product

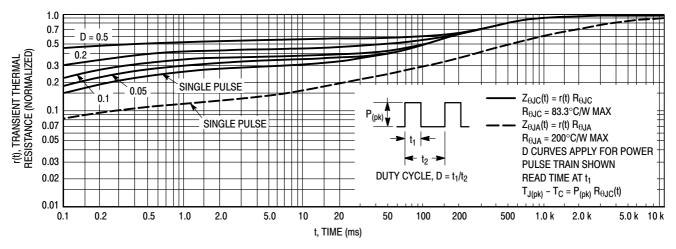


Figure 13. Thermal Response

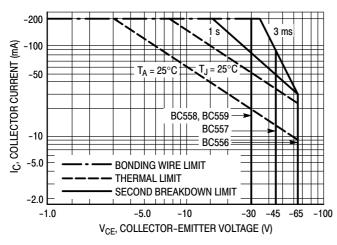


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^{\circ}\text{C}$; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
BC856ALT1		SOT-23	
BC856ALT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC856ALT3	3A	SOT-23	
BC856ALT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC856BLT1		SOT-23	
BC856BLT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC856BLT3	3B	SOT-23	
BC856BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

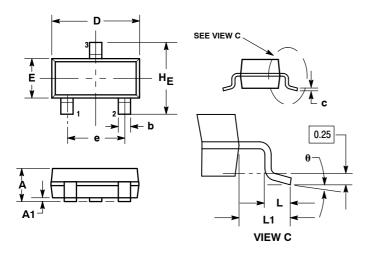
ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
BC857ALT1		SOT-23	
BC857ALT1G	3E	SOT-23 (Pb-Free)	0 000 /T 0 PI
BC857BLT1		SOT-23	3,000 / Tape & Reel
BC857BLT1G		SOT-23 (Pb-Free)	
BC857BLT3	3F	SOT-23	
BC857BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC857CLT1		SOT-23	
BC857CLT1G	3G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC857CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC858ALT1		SOT-23	
BC858ALT1G	3J	SOT-23 (Pb-Free)	0 000 (Table 9 Back
BC858BLT1		SOT-23	3,000 / Tape & Reel
BC858BLT1G	3К	SOT-23 (Pb-Free)	
BC858BLT3		SOT-23	
BC858BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC858CLT1		SOT-23	
BC858CLT1G	3L	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC858CLT3		SOT-23	
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC859BLT1		SOT-23	
BC859BLT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC859BLT3	4B	SOT-23	
BC859BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC859CLT1		SOT-23	
BC859CLT1G	40	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC859CLT3	4C	SOT-23	
BC859CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD

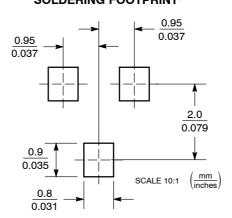
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

PIN 1. BASE

2. EMITTER COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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